

- ⊙ Each problem is 15 points. There is a 10-point bonus.
 - ⊙ Use words, equations, and/or figures to help you clarify an explanation.
1. The intrinsic carrier concentration in a Si is $n_i=1.5 \times 10^{10}$ atoms/cm³. After doping, the hole and electron concentrations become p and n . Assume the Si is doped with $N_d=10^{17}$ As atoms/cm³, use the mass-action law to find out the hole concentration. (In this heavily doped case, $N_d \gg n_i$, one can approximate $n=N_d$)
 2. (a) Roughly draw the distributions of magnetic field $B(r)$ and superconducting current density $n_s(r)$ near the center of a vortex. (b) Assume the penetration length and the coherence length of a type-II superconductor is λ and ξ . Estimate the critical magnetic fields H_{c1} and H_{c2} . Briefly explain.
 3. Explain, as clearly as you can, the AC Josephson effect. Also explain why it is a very sensitive sensor for tiny change of voltage.
 4. Assume that $\vec{k} \cdot \vec{E} \neq 0$, then from Gauss' law, the equation of continuity, and Ohm's law, show that $4\pi\sigma(\omega)\rho(\omega) = i\omega\rho(\omega)$. Explain why this leads to $\varepsilon = 0$. This shows that the longitudinal component of an electromagnetic wave can exist only when $\varepsilon = 0$.
 5. Explain, briefly but clearly, with the help of figures or equations, why the electron-electron scattering rate in metal is proportional to T^2 .
 6. The electric susceptibility for a collection of bounded oscillators is

$$\chi(\omega) = \frac{1}{V} \sum_j \frac{e^2}{m(\omega_j^2 - \omega^2 - i\eta_j\omega)}$$

In order to apply this result to a metal, we can consider the case with *identical* oscillators, and take the limit with $\omega_j = 0$, η being very small. With the help of the susceptibility, write down the electric conductivity $\sigma(\omega)$, then verify the Ferrel-Glover sum rule (ω_p is the plasma frequency):

$$\int_0^\infty \sigma'(\omega) d\omega = \frac{\omega_p^2}{8}$$

Note: $\varepsilon = 1 + 4\pi i\sigma/\omega$